Interferometric Optical Gyroscope Based on an Integrated Si₃N₄ Low-Loss Waveguide Coil

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Abstract—We describe the measurement and characterization of an interferometric optical gyroscope that uses an integrated 3-m large-area silicon nitride waveguide coil with waveguide loss <0.78 dB/m that is compatible with wafer-scale integration. The angle random walk and bias instability were measured to be $8.52^{\circ}/h^{1/2}$ and $58.7^{\circ}/h$, respectively. The measured performance is comparable to that of a commercial rate grade gyroscope, demonstrating that chip-scale integration is a feasible path to low cost, low power, compact implementation of optical gyroscope, and realization of longer coils will expand use of this technology to more demanding navigation applications.

Index Terms—Gyroscopes, inertial navigation, large area waveguide coils, optical sensors, ultra-low loss lithographic stitching.

I. INTRODUCTION

S ENSORS used in the fields of guidance and navigation have been undergoing continuous development for more than six decades [1]. Advancements in gyroscope technologies have been instrumental in the realization of high precision inertial motion units (IMUs) and inertial navigation systems (INSs). While the accuracy and performance are important, many applications in navigation today require reduced size, cost, and operating power of the inertial sensor in addition to their accuracy [2]. Smaller sensors enable and impart guidance, navigation, and control into miniaturized, smart, self-guiding systems such as drones which were previously considered unrealizable. Based on their quality and performance, gyroscopes are categorized in to different grades as listed in Table I. Microelectromechanical (MEMS) gyroscopes, ring laser gyroscopes (RLGs), and interferometric fiber optic gyroscopes (IFOGs) are among the

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 TABLE I

 CLASSIFICATION OF GYROSCOPES BY PERFORMANCE [4]

Туре	Angle random walk (deg/√hr)	Bias instability (deg/hr)
Rate grade (this work)	> 0.5	10 to 1000
Tactical grade	0.5 to 0.05	1 to 10
Intermediate grade	0.05 to 0.005	0.01 to 1
Inertial grade	< 0.005	< 0.01
Strategic grade	< 0.0003	< 0.001

commercially mature and available technologies today that are widely used in navigation, tactical, and industrial applications.

While optical gyroscopes have traditionally been expensive, their decreased vibrational sensitivity and rate random walk makes them superior to their MEMS counterparts. Accordingly, MEMS sensors are widely used in commercial and rate grade sensor applications requiring lower sensitivity at reduced cost and RLGs are employed as tactical and navigation grade sensors in IMUs [3]. Based on the design and performance, IFOGs can range from low cost, smaller area industrial rate grade sensors to expensive large area strategic or precision grade devices to be used in IMU/INS systems [4]. This versatility has attracted considerable research in the size reduction of interferometric optical gyroscopes (IOGs) while maintaining their high sensitivity and performance specifications. However, the cost and complexity of assembling high quality fiber optic based gyroscopes requiring precision alignment and assembly of discrete optical components, and sensitivity to manufacturing and environmental variations has led to an increased need to integrate them at the chip-scale.

The performance of an IOG improves with increased enclosed area and is degraded by the limited polarization extinction of the optical coils. Chip scale integration can improve the manufacturability of IOGs in general, while at the same time addressing polarization misalignment issues and significantly reducing the size, weight, and cost. It has been challenging to realize an on-chip waveguide coil based IOG with desired performance due to the absence of an integration platform that realizes very low waveguide loss over the required large on-chip coil lengths, a high degree of polarization selectivity and integration with other key elements like fiber to waveguide mode transformers and low loss waveguide crossings. The Si_3N_4 based ultra-low loss waveguide (ULLW) platform [4], [5] provides a wafer-

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Fig. 1. Minimum reciprocal configuration of an IFOG (polarizer being an optional component). Physical dimensions and type of the sensing coil is varied based on the targeted application of sensor.

scale compatible solution to enable long, on-chip waveguide coils with losses as low as 0.1 dB/m [5]. In addition to the low waveguide loss and high polarization dependent loss (>75 dB) of ULLW Si₃N₄ coils [7], the low nonlinear loss and high nonlinearity thresholds (compared to other waveguide platforms) [8], play an important role in minimizing parasitic effects due to the optical Kerr effect, and non-reciprocal polarization drift normally associated with using bulk optical components, thus resulting in improved gyroscope performance. A chip scale IOG can be achieved by three dimensional close-packed multi-chip integration of waveguide coil and integrated front-end chips. A fully integrated IOG can be realized by integrating the gyroscope front-end and low loss waveguide coil onto a single chip thereby exploiting the passive and active function of integrated front ends with the low loss of Si₃N₄ coils. The Si₃N₄ waveguide coil based gyroscope with active optical components on a heterogeneously integrated III/V-Silicon platform has been proposed and analyzed in [9]. Detailed design and characterization of integrated optical components for a IOG are presented in [10]. We reported the preliminary results of a Sagnac sensor realized using this ultra-low loss high aspect ratio Si₃N₄/SiO₂ planar waveguide coil in our previous work [11].

This paper is an extended version of our submission to OFS- 25 which can be found at [12]. In this paper, we present a more detailed view of design and characterization of low loss integrated waveguide coil based gyroscope. We also discuss two approaches to integrate the optical active components with waveguide coil to realize an on-chip gyroscope sensor. We begin with the general setup for an IFOG in Section II followed by the design, fabrication, and packaging of waveguide coil in Section III. Section IV discusses the rotation rate measurements and noise characterization of gyroscope. The prospects for full integration and improvements in gyroscope performance using a longer coil with lower packaging losses are discussed in Section V followed by the summary and conclusion of the work.

II. OVERVIEW OF DESIGN AND PERFORMANCE OF IOG

The interferometric optical gyro operates on the principle of Sagnac phase shift [4]. The Sagnac phase shift $\Delta \varphi_R$ induced due to rotation in an IOG about the axis with rate Ω , as illustrated in Fig. 1, is given by

$$\Delta \Phi_{\rm R} = \left(\frac{8\pi}{\rm c} \cdot \lambda\right) \cdot A_{\rm enc} \cdot \Omega \tag{1}$$

$$\mathbf{A}_{\rm enc} = \mathbf{N} \cdot \mathbf{A} \tag{2}$$



Fig. 2. (Left) Illustration of Archimedian waveguide spiral for an IOG. (Right) Cross section of ULLW structure with 40-nm core to achieve lowest propagation loss.

where A_{enc} is the area enclosed in the sensing coil, λ is the mean wavelength of the optical source, and Ω is the rotation rate. For an IFOG, area enclosed is the sum of areas of each turn of the fiber sensing coil as shown in (2), where N is the number of turns and A is area enclosed by an individual turn of the coil.

The performance for a given enclosed area of sensing coil of an IOG is limited by the propagation loss and intrinsic noise sources that affect the performance including detected thermal noise and shot noise, laser relative intensity noise and un-desired interferometric effects that interfere with the desired detected signal, such as coherent backscattering and reflections, the optical Kerr effect, and polarization non-reciprocities [9]. The phase shift induced by these non-reciprocities degrades the angle random walk and bias instability of the IOG. To address nonreciprocal polarization effects, polarization maintaining (PM) fiber and components can be employed, however the net polarization bias error is limited by the polarization extinction ratio (PER) of the sensing coil, the intensity rejection ratio of the polarizer and manufacturing and environment polarization misalignment and induced polarization coupling.

The RMS value of polarization bias error $\sigma_{\Delta\varphi e}$ induced by a sensing coil of length, L, mean rate of power transfer between the polarization modes h (PER = h.L), depolarization length L_d , and intensity rejection ratio of polarizer ε^2 is given by [4]

$$\sigma_{\Delta\varphi e} = \frac{\varepsilon^2 h L}{\sqrt{N}} \tag{3}$$

where $N = L/L_d$ is the number of depolarization lengths. While the typical ε^2 of a fiber polarizer is limited to around 25–30 dB, high aspect ratio 40-nm core Si₃N₄ waveguides have been shown to have PERs >75 dB [7], indicating a suppression of the polarization bias error by more than 4 orders of magnitude.

III. INTEGRATED GYROSCOPE

A. Integrated Coil Design and Fabrication

The design goal for waveguide coil to be used in an IOG is to realize largest possible area of coil with lowest possible attenuation. This translates to choosing an optimal length for a given waveguide loss to meet the required area and hence, desired gyroscope sensitivity. Archimedian spirals as shown in Fig. 2, are ideal geometry to achieve maximum enclosed



Fig. 3. Estimation of angle random walk for varying coil length.

area and length for a given chip footprint. For an Archimedian spiral defined by $\rho = a + b\theta$, where a is the minimum radius and $b = \frac{1}{2\pi} x$ turn radius difference, and N turns, the effective enclosed area is given by

$$A_{enc} = \iint \rho \, d\rho \, d\theta = \frac{1}{2} \int_0^{2N\pi} \rho^2 d\theta$$
$$= N\pi \left[a^2 + \frac{b^2}{3} (2N\pi)^2 + 2N\pi ab \right]$$
(4)

The use of thinner waveguide cores improves propagation and crossing losses (assuming operating in the region where sidewall roughness is the dominant contribution to both these characteristics) but places a limitation on the minimum waveguide bend radius [5]. Here we choose a waveguide structure with 40-nm thick Si₃N₄ core, shown in Fig. 2 to give us minimal possible loss values, which constrains our bend radius to 11 mm. The lithographic stepper system ASML PAS 5500 DUV used in our fabrication process has a maximum die size of 21 × 25 mm that limited the bend radius to 10 mm within a single field. To overcome the limitation of die size of our DUV stepper and to realize a large area coil, we used ultra-low loss stitching [13] of 4 different DUV fields which increased the achievable coil radius to 20 mm.

Using (4) and the approach described in [9], the optimal length of the ULLW Si₃N₄ coil to be used in an integrated optical gyroscope to achieve ARW close to 1 deg/ \sqrt{hr} was estimated as shown in Fig. 3 to be about 3–10 m. The simulated value accounts for an excess packaging loss of 1 dB/m, RIN of –128 dBc/Hz and waveguide loss of 0.8 dB/m using an optical input power of 100 mW. The estimated ARW of IOG with a 3-m integrated waveguide coil used in this paper, as shown in Fig. 3, is close to 1.15 deg/ \sqrt{hr} .

The design parameters for fabricating the waveguide coil with $40 \text{ nm} \times 7 \mu \text{m}$ waveguide coil used in this paper are summarized in Table II. Fabricated coil and crossing structures are shown in Fig. 4.

Waveguide loss of the coil was characterized using optical backscattering reflectometry (OBR). Different loss sources contributing to the total loss of the waveguide coil are listed in Table III. Complete details about the large area waveguide coil design and characterization can be found in [13], [14].

TABLE II Summary of Waveguide Coil Design Parameters

	Value	
Coil length	3 m	
Outer radius	20 mm	
Inner radius	17.25 mm	
Waveguide spacing	50 µm	
Number of crossings	50	
Enclosed area	278 cm^2	
Estimated ARW	1.15 deg/√hr	



Fig. 4. (Left) Top view of fabricated 3 m waveguide coil illuminated using a red laser. (Right) Dark field optical image of 90° crossings of the fabricated spiral.

 TABLE III

 Summary of Loss Contributions in Waveguide Coil [14]

	Value
Waveguide and stitching loss*	0.78 dB/m
Crossing loss	0.0156 dB/crossing

* indicates the minimum waveguide and stitching loss measured at 1595 nm. At 1550 nm, waveguide loss is close to 1.5 dB/m. Estimated ARW for a waveguide loss of 1.5 dB/m, measured RIN of -122 dBc/Hz, and an excess packaging loss of 12 dB was around 2.23 deg/ \sqrt{hr} .



Fig. 5. (Left) Illustration of the 3-m Si_3N_4 waveguide coil edge coupled to PM fibers using a VGA. (Right) Actual packaged coil with FC/APC connectors (used to minimize reflections).

B. Packaged Coil

To assess the performance of waveguide coil as the sensing element in a gyroscope, we packaged the coil and mounted it on a rotation stage for measurements. In order to reduce the polarization induced drift and to improve stability of device packaging, a custom-made V-groove array (VGA) was used to house polarization maintaining fibers which were edge coupled to Si_3N_4 waveguides as shown in Fig. 5. Dymax epoxies OP-54 and



Fig. 6. Setup for characterization of gyroscope based on a waveguide (WG) coil. SRS 844 lock-in was used for demodulation and a National instruments (NI) data acquisition (DAQ) was used to collect the output data.

OP-67-LS were used to put the VGA in place after alignment followed by a UV curing procedure using Dymax Bluewave 75 to bond the VGA to the plate. The mode mismatch between highly elliptical mode of our untapered waveguide and nearly circular mode of the fiber resulted in increase of fiber-chip coupling loss. In addition, the drift of the fibers post UV cure increased the coupling loss further, causing a total loss of >6 dB per facet, resulting in a total insertion loss for the waveguide coil to be 16.2 dB with a broadband source for the packaged device.

IV. GYROSCOPE CHARACTERIZATION AND PERFORMANCE MEASUREMENTS

A. Proper Frequency

The rotation rate output of an IOG is evaluated using the amplitude of first harmonic of bias modulation frequency in the output of the reflected signal. To achieve perfect rejection of all the even harmonics, realize maximum sensitivity, and suppress other parasitic noise sources, the bias modulation should be at a frequency f_p , which is the inverse of twice the transit delay, $\Delta \tau_g$ of the sensing coil.

$$f_{\rm p} = \frac{1}{2 \cdot \Delta \tau_{\rm g}} \tag{5}$$

This frequency is known as the proper (eigen) frequency [4], [11], [12] of the coil where the gyroscope operates with maximum sensitivity. We utilized square wave biasing scheme to further suppress the spurious effects due to nonlinear response of modulator [4]. The gyroscope characterization was performed using an in-house assembled setup is shown in Fig. 6. Two 20 dB ZFL-1000LN RF amplifiers were cascaded between the photo detector and the lock-in amplifier to improve the signal to noise ratio. The time constant and filter slope for demodulation using lock-in were set to 300 ms and 24 dB/octave respectively.

The proper frequency of our waveguide coil gyroscope, determined by performing a ramp frequency sweep (as described in our previous paper [11]]), was found to be 21.02 MHz (shown in Fig. 7.) The measured value agrees well with the expected value of proper frequency based on actual length of the sensing coil (3 m waveguide coil + fiber pig tails \sim 5 m).

B. Rotation Signal Measurement and Noise Characterization

To correlate the measured output value of gyroscope to the input rotation rate, we placed the setup on a calibrated rotation



Fig. 7. Measured proper frequency of the sensing coil with 3-m Si_3N_4 waveguide in the loop and about 2-m PM fiber pig tails.



Fig. 8. Measured output was quite linear with the input rotation rate and the difference in scale factor between CW and CCW rotation rates was very small.

stage and measured the scale factor of the sensor. To accomplish this, we used a high precision rotation stage (Ideal Aerosmith 1270VS) and the applied rotation rate was swept from 0.02 deg/sec to 10 deg/sec in both CW and CCW directions. The scale factor was measured to be approximately 335 mV/deg/sec, as shown in Fig. 8.

The detection limit of the gyroscope was characterized with the setup at rest using the standard Allan deviation technique [15]. The samples were captured using NI-DAQ at a rate of 50 Hz for an hour. The plot of Allan variance for one hour of data is shown in Fig. 9. A -0.5-slope line was fit to the data to extract the angle random walk or the detection limit of the system to be 8.52 deg/ \sqrt{hr} . The bias instability of the gyroscope is evaluated from the flat portion (slope = 0) of the Allan deviation plot. As seen in, there is a flat portion (A) at 0.03 hr which gives a BIS of 58.68 deg/hr and another flat portion (B) at around 0.1 hr, which yields a BIS of 45.42 deg/hr before noise becomes predominantly rate random walk (slope = 1).

To further verify the value of bias instability, we performed an Allan deviation measurement for five hours at a sample rate of 10 Hz and lock-in time constant of 3 s. The flat portion on this Allan deviation plot was observed at 0.034 hr as shown in Fig. 10 yielding a BIS of 68.4 deg/hr which is closer to the



Fig. 9. Allan deviation measurement with lock-in time constant of 300 ms, with a filter slope of 24 dB/octave and a sampling rate of 50 Hz.



Fig. 10. $\sigma 1(\tau)$ and $\sigma 2(\tau)$ refer to the Allan deviation measurements with time constant of 300 ms and 3 s, respectively; Allan deviation is valid only from $\tau = (1/\text{ENBW})$ s.

TABLE IV SUMMARY OF MEASUREMENTS

$ au_{int}$ (ms)	ENBW (Hz)	SF (V/deg/sec)	ARW (deg/√hr)	BIS (deg/hr)	f _{sam} (Hz)
300	0.26	0.335	8.52	58.68	50
3	0.026	0.33	8.7	68.4	10

 $\tau_{\rm int} = {\rm Lock-in}$ time constant; ENBW = Effective noise bandwidth for filter slope of 24 dB/oct; SF = scale factor; $f_{\rm s\,am}$ is the DAQ sampling rate; ENBW = $(5/64\tau_{\rm int})$ for a filter slope of 24 dB/oct.

58.68 deg/hr measured in region (A) of Fig. 9. High value of bias instability suggests that 1/f flicker noise from electrical components to be the dominant noise source. Summary of all gyroscope measurements is given in Table IV.

V. PROSPECTS FOR FULL INTEGRATION AND PACKAGING

Integration of active optical components along with the waveguide coil will help us realize a chip scale version of IOG.

While broadband sources are the preferred optical sources for most of the commercial IFOGs because of their immunity to several noise sources of gyro such as coherent backscattering [4], use of a laser that is spectrally broadened with direct [16]–[19] or external [20], [21] frequency/phase modulation has attracted considerable attention in the recent years. Because of their advantages such as smaller footprint, higher power efficiency, and higher wavelength stability (that translates to higher scale factor stability), a frequency modulated (FM) laser will be a more



Fig. 11. Schematic of the proposed fully multichip IOG with integrated frontend chip placed in a deep-etch SiO_2/Si trench on the waveguide coil chip. Mode converters on both the chips help in realizing smaller coupling losses.

Si waveguide		Si ₃ N ₄ waveguide		Si waveguide dimensions 200 nm x 269 nm	
			•	Si3N4 waveguide (WxH)	Power coupling (%)
			•	7 um x 40 nm	64.88
				2.8 um x 40 nm	61.73
				2.8 um x 90 nm	92.3
z (micrens)		z (microna)	-0.8 -0.4 -0.2 0.9		

Fig. 12. Example design of mode converters (using mode solutions in Lumerical [22]) between Si_3N_4 and Si waveguides showing the power coupling efficiency for different geometries of Si_3N_4 waveguide.

suitable candidate for a chip scale gyroscope. An integrated photonic chip with an optical source, two couplers, three photodiodes, and two phase modulators within an area of 4.5 mm^2 that can be used to realize a chip scale gyroscope was demonstrated by the authors, details of which can be found in [10].

Multi-chip photonic integration of the low loss waveguide coil and integrated front-end chip can be used to realize a chip scale IOG. The integrated front-end chip can be placed in a deepetch cavity on the waveguide coil chip, aligned and epoxied to realize a hybrid chip version of IOG as shown in Fig. 11.

With customized tapers designed for both Si_3N_4 and Si waveguides as shown in Fig. 12, the low loss waveguide coil can be coupled with the integrated front-end with minimal coupling losses.

A fully integrated waveguide coil based gyroscope can be realized using vertical coupling between Si_3N_4 and Si waveguide layers. Such coupling can be used to integrate Si_3N_4 waveguide coil with the integrated front-end. Coupling losses of (0.4 \pm 0.2) dB per transition between silicon and ULLW layers have been demonstrated in [23] that would provide a solution to alleviate the high fiber to waveguide coupling loss through seamless chip scale integration of all IOG components (III–V/Si actives with ULL Si_3N_4 coils) and realize a fully integrated waveguide coil based interferometric optical gyroscope as shown in Fig. 13. The phase modulator is operated in push-pull configuration using two electrodes (yellow) to reduce driving voltage and jitter improving the power efficiency and performance of the sensor.



Fig. 13. Schematic of proposed fully integrated optical waveguide gyroscope with a ULLW coil in Si_3N_4 with heterogenous III/V-Si front-end.

VI. CONCLUSION

We reported the rotation rate measurements of an interferometric optical gyroscope using an ultra-low loss Si₃N₄ waveguide coil. The measured gyroscope sensitivity (ARW = 8.52 deg/ \sqrt{hr}) was found to be in the same order as that of a commercial rate grade sensor. Reduction of flicker noise by using low noise electrical components and decrease in the total packaging loss to less than 1 dB (currently 12 dB) will greatly improve the performance of gyroscope and bridge the mismatch between values of measured and simulated sensitivity. We estimated that the ARW can be reduced to 0.52 deg/ \sqrt{hr} for the current 3 m coil by decreasing the RIN of optical source from -128 dBc/Hz to -140 dBc/Hz. This suggests that use of a frequency/phase modulated laser source, because of its low RIN, can result in significantly better gyroscope performance. Simulations in [13], [14] show that further improvements in waveguide losses and increase in the waveguide coil length (15 m) using a broadband source with 100 mW of optical power having a RIN of -128 dBc/Hz will push the sensitivity down to that of a tactical grade sensor (ARW = $0.475 \text{ deg}/\sqrt{\text{hr}}$). Reduction in waveguide propagation loss enables realization of larger area coils that can further improve the performance of the sensor. In conclusion, results show that ultra-low loss waveguide coils offer a promising solution to realize a fully integrated waveguide optical gyroscope (IWOG) as shown in Fig. 13 that is resilient to several noise factors such as errors related to optical non-linearities and polarization drift.

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